

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.24\text{ V}$ at $I_F = 5\text{ A}$



TO-3PW



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
V_{RRM}	45 V
I_{FSM}	400 A
V_F at $I_F = 30\text{ A}$ ($T_A = 125\text{ °C}$)	0.41 V
T_J max.	150 °C
Package	TO-3PW
Diode variations	Dual common cathode

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VT60L45PW	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	45	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	60	A
		30	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	400	A
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.37	-	V
	I _F = 15 A			0.43	-	
	I _F = 30 A			0.49	0.57	
	I _F = 5 A	T _A = 125 °C		0.24	-	
	I _F = 15 A			0.32	-	
	I _F = 30 A			0.41	0.50	
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	7	mA
		T _A = 125 °C		67	180	mA

Notes

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
(2) Pulse test: Pulse width $\leq 5\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VT60L45PW	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	0.9	$^{\circ}\text{C/W}$
	per device		0.6	
	per device	$R_{\theta JA}^{(1)(2)}$	48	

Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
(2) Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-3PW	VT60L45PW-M3/4W	4.5	4W	30/tube	Tube

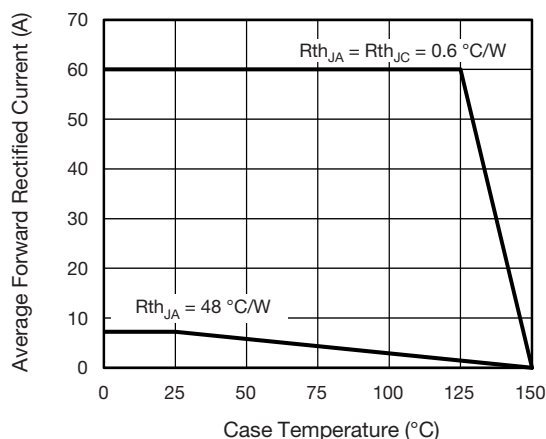
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

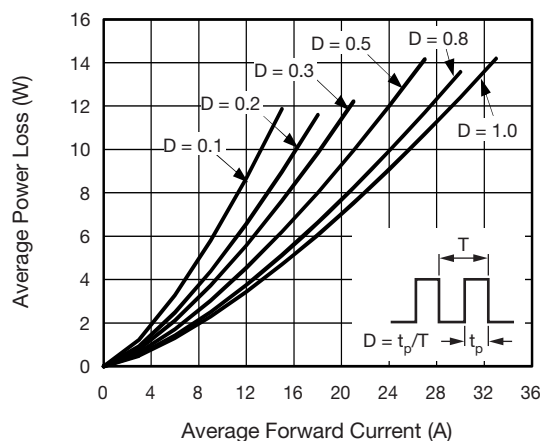


Fig. 2 - Forward Power Loss Characteristics Per Diode

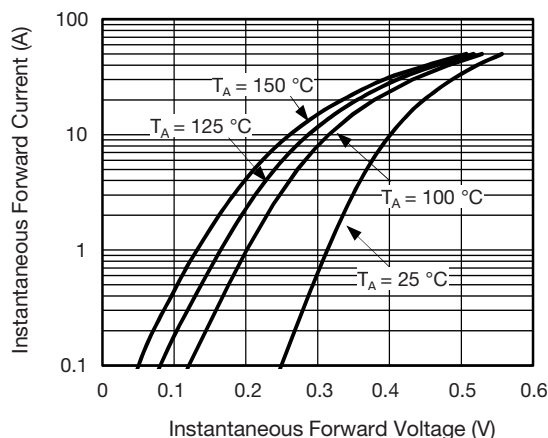


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

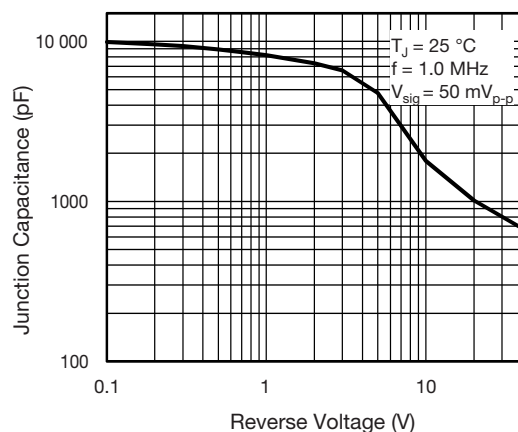


Fig. 5 - Typical Junction Capacitance Per Diode

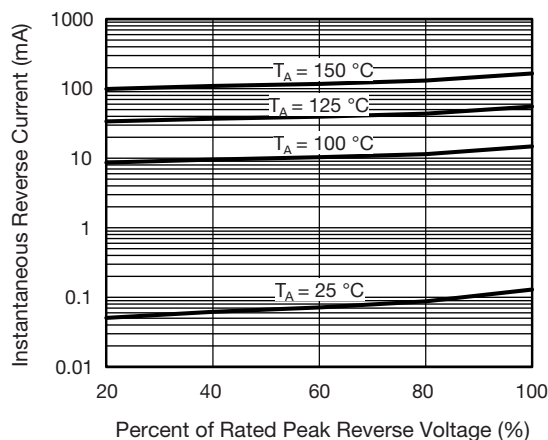


Fig. 4 - Typical Reverse Characteristics Per Diode

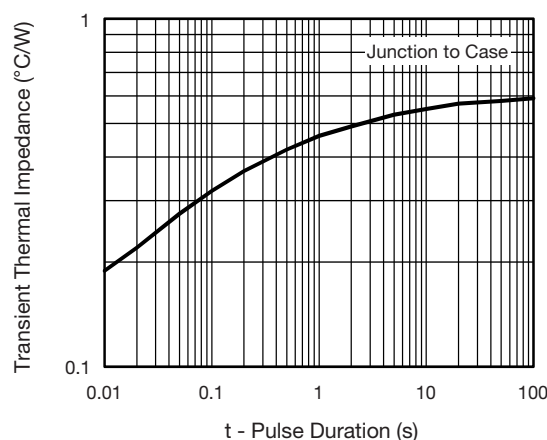
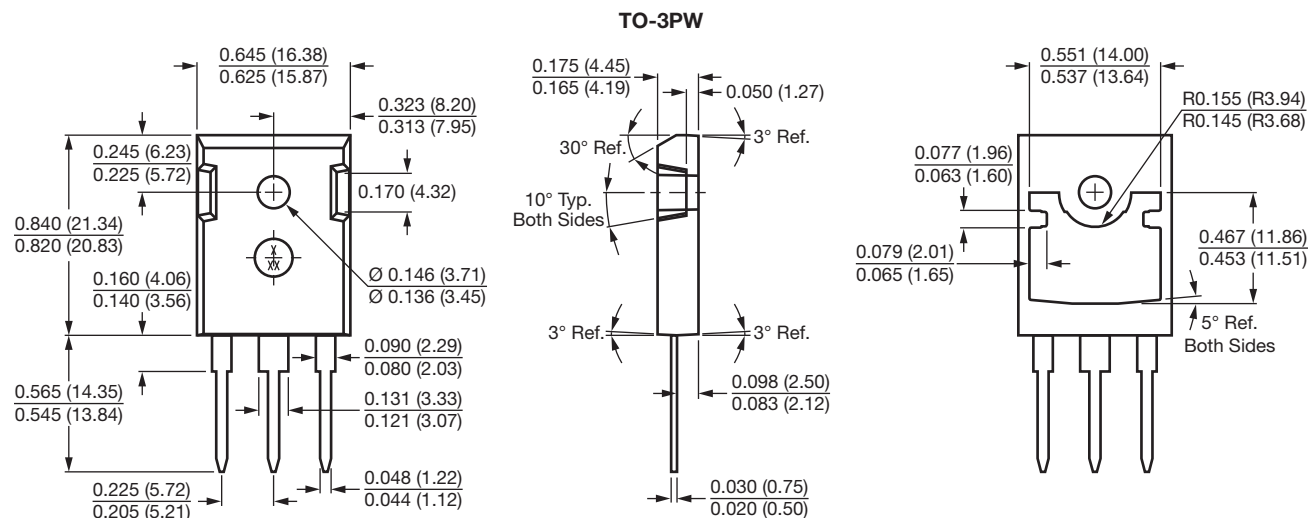


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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